

TOSHIBA PHOTOCOUPLER GaAlAs IRED + PHOTO-IC

**T L P 5 5 9 ( I G M )**

TRANSISTOR INVERTOR

INVERTER FOR AIR CONDITIONER

LINE RECEIVER

IPM INTERFACES

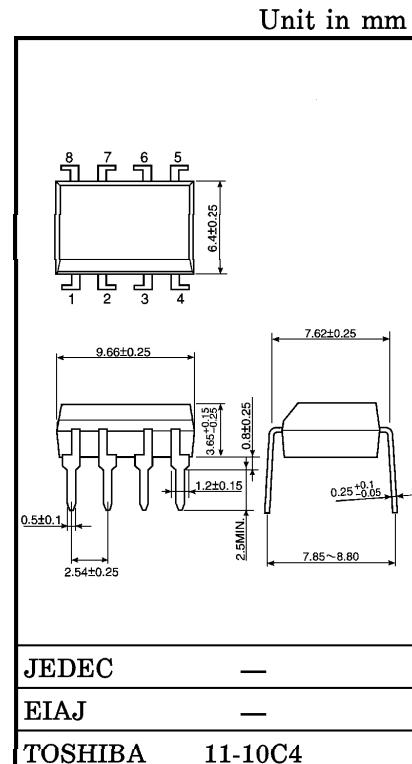
The TOSHIBA TLP559 (IGM) consists of a GaAlAs high-output light emitting diode and a high speed detector of one chip photo diode-transistor.

This unit is 8-lead DIP package.

TLP559 (IGM) has no internal base connection, and a Faraday shield integrated on the photodetector chip provides an effective common mode noise transient immunity.

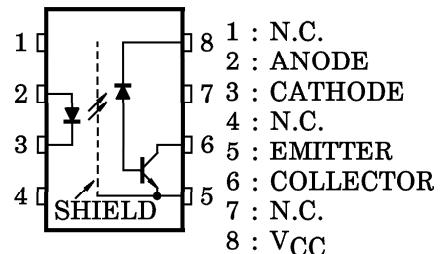
TLP559 (IGM) guarantees minimum and maximum of propagation delay time, switching time dispersion, and high common mode transient immunity. Therefor TLP559 (IGM) is suitable for isolation interface between IPM (Intelligent Power Module) and control IC circuits in motor control application.

- Isolation Voltage : 2500V<sub>rms</sub> Min.
- Common Mode Transient Immunity  
:  $\pm 10\text{kV}/\mu\text{s}$  Min.  
@ V<sub>CM</sub>=1500V
- Switching Time  
: t<sub>pHL</sub>, t<sub>pLH</sub>=0.1 $\mu\text{s}$  Min.  
=0.8 $\mu\text{s}$  Max.  
@ IF=10mA, V<sub>CC</sub>=15V, R<sub>L</sub>=20k $\Omega$ , Ta=25°C
- Switching Time Dispersion : 0.7 $\mu\text{s}$  Max.  
(|t<sub>pLH</sub>-t<sub>pHL</sub>|)
- TTL Compatible
- UL Recognized : UL1577, File No.E67349

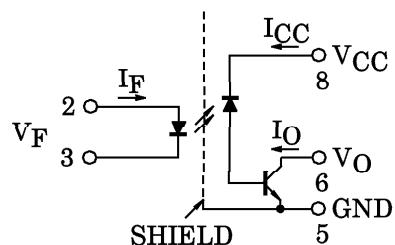


Weight : 0.54g

## PIN CONFIGURATION (Top view)



## SCHEMATIC



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● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current (Note 1)	$I_F$	25	mA
	Pulse Forward Current (Note 2)	$I_{FP}$	50	mA
	Peak Transient Forward Current (Note 3)	$I_{FPT}$	1	A
	Reverse Voltage	$V_R$	5	V
	Diode Power Dissipation (Note 4)	$P_D$	45	mW
Detector	Output Current	$I_O$	8	mA
	Peak Output Current	$I_{OP}$	16	mA
	Output Voltage	$V_O$	-0.5~20	V
	Supply Voltage	$V_{CC}$	-0.5~30	V
	Output Power Dissipation (Note 5)	$P_O$	100	mW
Operating Temperature Range		$T_{opr}$	-55~100	$^\circ\text{C}$
Storage Temperature Range		$T_{stg}$	-55~125	$^\circ\text{C}$
Lead Solder Temperature (10s) (Note 6)		$T_{sol}$	260	$^\circ\text{C}$
Isolation Voltage (AC, 1min., R.H. $\leq 60\%$ , $T_a = 25^\circ\text{C}$ ) (Note 7)		$BV_S$	2500	$V_{rms}$

(Note 1) : Derate 0.8mA above  $70^\circ\text{C}$ .(Note 2) : 50% duty cycle, 1ms pulse width.  
Derate 1.6mA /  $^\circ\text{C}$  above  $70^\circ\text{C}$ .(Note 3) : Pulse width  $PW \leq 1\mu\text{s}$ , 300pps.(Note 4) : Derate 0.9mW /  $^\circ\text{C}$  above  $70^\circ\text{C}$ .(Note 5) : Derate 2mW /  $^\circ\text{C}$  above  $70^\circ\text{C}$ .

(Note 6) : Soldering portion of lead : up to 2mm from the body of the device.

(Note 7) : Device considered a two terminal device : pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

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- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
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- The information contained herein is subject to change without notice.

ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = 16\text{mA}$	—	1.65	1.85	V
	Forward Voltage Temperature Coefficient	$\Delta V_F / \Delta T_a$	$I_F = 16\text{mA}$	—	-2	—	$\text{mV} / {}^\circ\text{C}$
	Reverse Current	$I_R$	$V_R = 5\text{V}$	—	—	10	$\mu\text{A}$
	Capacitance between Terminal	$C_T$	$V_F = 0, f = 1\text{MHz}$	—	45	—	pF
Detector	High Level Output Current	$I_{OH}(1)$	$I_F = 0\text{mA}, V_{CC} = V_O = 5.5\text{V}$	—	3	500	nA
		$I_{OH}(2)$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$ $V_O = 20\text{V}$	—	—	5	$\mu\text{A}$
		$I_{OH}$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$ $V_O = 20\text{V}, T_a = 70^\circ\text{C}$	—	—	50	
	High Level Supply Voltage	$I_{CCH}$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$	—	0.01	1	$\mu\text{A}$
	Supply Voltage	$V_{CC}$	$I_{CC} = 0.01\text{mA}$	30	—	—	V
	Output Voltage	$V_O$	$I_O = 0.5\text{mA}$	20	—	—	V

COUPLED ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	$I_O / I_F$		$I_F = 10\text{mA}, V_{CC} = 4.5\text{V}$ $V_O = 0.4\text{V}$	25	35	75	%
			$I_F = 16\text{mA}, V_{CC} = 4.5\text{V}$ $V_O = 0.4\text{V}, T_a = -25\text{--}100^\circ\text{C}$	15	—	—	
Low Level Output Voltage	$V_{OL}$		$I_F = 16\text{mA}, V_{CC} = 4.5\text{V}$ $I_O = 2.4\text{mA}$	—	—	0.4	V

ISOLATION CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	$C_S$		$V = 0, f = 1\text{MHz}$ (Note 8)	—	0.8	—	pF
Isolation Resistance	$R_S$		$R.H. \leq 60\%, V_S = 500\text{V}$ (Note 8)	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage	$BVS$	AC, 1 minute		2500	—	—	$V_{rms}$
		AC, 1 second, in oil		—	5000	—	$V_{dc}$
		DC, 1 minute, in oil		—	5000	—	

SWITCHING CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ ,  $V_{CC} = 15\text{V}$ )

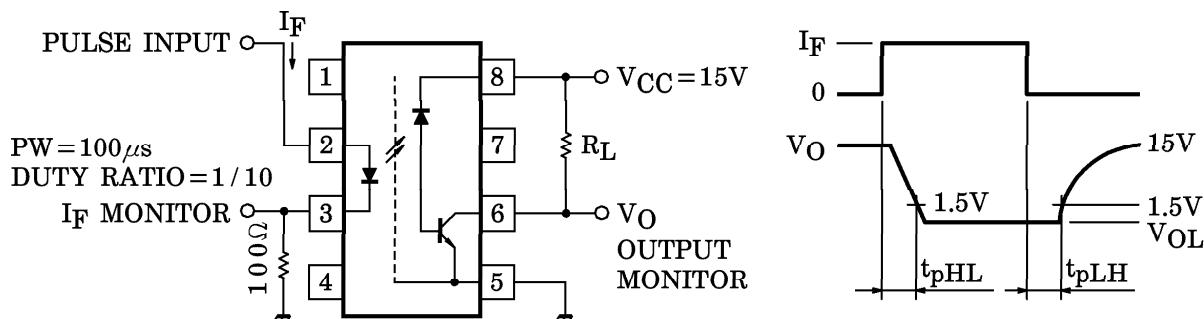
CHARACTERISTIC	SYMBOL	TEST CIR-CUTT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation Delay Time ( $H \rightarrow L$ )	$t_{pHL}$	1	$I_F = 0 \rightarrow 10\text{mA}$ , $R_L = 20\text{k}\Omega$	0.1	0.45	0.8	$\mu\text{s}$
Propagation Delay Time ( $L \rightarrow H$ )	$t_{pLH}$		$I_F = 0 \rightarrow 10\text{mA}$ , $R_L = 20\text{k}\Omega$ $T_a = 0 \sim 85^\circ\text{C}$	0.1	0.45	0.9	
Switching Time Dispersion between ON and OFF	$ t_{pLH}-t_{pHL} $		$I_F = 0 \rightarrow 10\text{mA}$ , $R_L = 20\text{k}\Omega$ $T_a = -25 \sim 100^\circ\text{C}$	0.1	0.45	1.0	
Common Mode Transient Immunity at Logic High Output (Note 8)	$CM_H$	2	$I_F = 0\text{mA}$ $V_{CM} = 1500\text{V}_{\text{p-p}}$ $R_L = 20\text{k}\Omega$	10000	15000	—	$\text{V} / \mu\text{s}$
Common Mode Transient Immunity at Logic Low Output (Note 8)	$CM_L$		$I_F = 10\text{mA}$ $V_{CM} = 1500\text{V}_{\text{p-p}}$ $R_L = 20\text{k}\Omega$	-10000	-15000	—	$\text{V} / \mu\text{s}$

(Note 8) :  $CM_L$  is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state ( $V_O < 1\text{V}$ ).

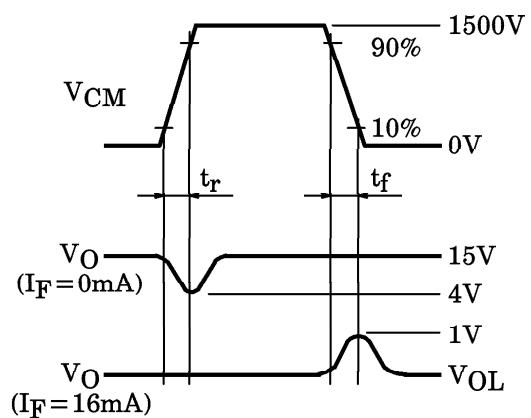
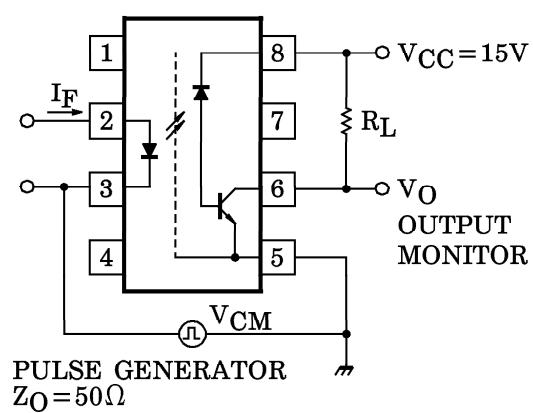
$CM_H$  is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ( $V_O < 4\text{V}$ ).

(Note 9) : Maximum electrostatic discharge voltage for any pins : 100V ( $C = 200\text{pF}$ ,  $R = 0$ ).

## TEST CIRCUIT 1 : Switching time test circuit



TEST CIRCUIT 2 : Common mode noise immunity test circuit



$$CM_H = \frac{1200 \text{ (V)}}{t_r \text{ (\mu s)}}, \quad CM_L = \frac{1200 \text{ (V)}}{t_f \text{ (\mu s)}}$$